



The TCS1360N01 uses deep trench technology to provide excellent  $R_{DS(ON)}$  and low gate charge. It can be used in a wide variety of applications.

## **General Features**

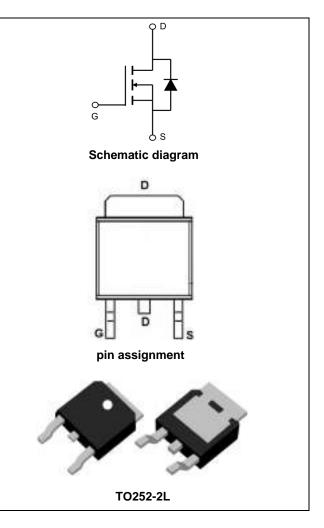
•  $V_{DS} = 30V$ ,  $I_D = 60A$ 

$$\begin{split} R_{DS(ON)} < 6.5 m\Omega & @V_{GS} = 10V \\ R_{DS(ON)} < 10.5 m\Omega & @V_{GS} = 4.5V \end{split}$$

- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

## **Application**

- Load Switch and Battery Protection
- Uninterruptible Power Supplies (UPS)
- Synchronous Rectification in DC/DC and AC/DC Converters



## Absolute Maximum Ratings (TC=25℃ unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	30	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	ID	60	А
Drain Current-Continuous (TC=100°C)	I <sub>D</sub> (TC=100°C)	40	А
Pulsed Drain Current (Note 1)	I <sub>DM</sub>	240	А
Maximum Power Dissipation	PD	50	W
Single Pulsed Avalanche Energy (L=0.1mH)	Eas	51	mJ
Operating Junction and Storage Temperature Range	$T_J, T_STG$	-55 To 150	°C

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	2.5	°C/W